

长春新产业光电技术有限公司

Changchun New Industries Optoelectronics Tech, Co., Ltd.

DATA SHEET

MDL-H-915/2000~5000mW

SPECIFICATIONS

INFRARED DIODE LASER AT 915nm

Diode infrared laser module at 915nm is made features of ultra compact, long lifetime, low cost and easy operating, which is used in measurement, communication, spectrum analysis, etc.



Wavelength (nm)	915±5		
Output power (mW)	>2000, 3000, 4000, , 5000		
Transverse mode	Near TE ₀₀		
Operating mode	CW		
Power stability (rms, over 4 hours)	<1%, <3%, <5%		
Warm-up time (minutes)	<5		
M ² factor	<20		
Beam divergence, full angle (mrad)	<3.0		
Beam diameter at the aperture (mm)	5~8		
Beam height from base plate (mm)	29		
Polarization ratio	>50:1		
Pointing stability after warm-up (mrad)	<0.05		
Operating temperature (°C)	10~35		
Power supply (90-264VAC)	PSU-H-LED	PSU-H-FDA	PSU-H-OEM
Modulation option	TTL/Analog 1Hz-5KHz, 1Hz-10KHz, 1Hz-30KHz, and TTL on/off		
Expected lifetime (hours)	10000		
Warranty period	1 year		



